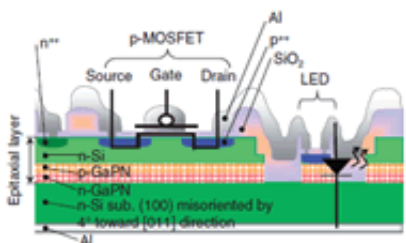


Silicon, nitride LEDs integrated onto a single chip for one-bit digital counters

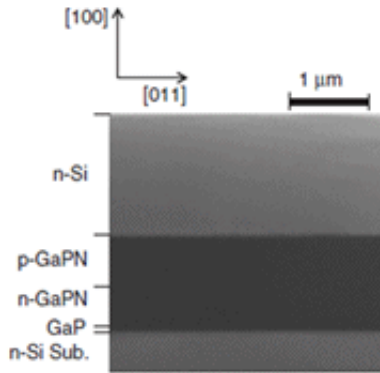
March 25 2011, By Adarsh Sandhu



One-bit counter consisting of a p-MOSFET and GaPN light emitting diode

Silicon-based semiconductor devices dominate the microelectronics industry and are used for the fabrication of high density integrated circuits comprising of memory and processing devices. However, silicon has an indirect band gap, which severely limits its use for fabricating photonic devices such as light emitting diodes (LEDs) and lasers.

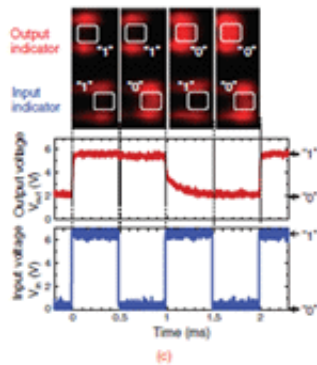
An innovative solution to this problem would be the integration of silicon devices with LEDs produced using direct [band gap](#) compound semiconductors, in the form of optoelectronic integrated circuits (OEICs).



Transmission electron microscope image showing the n-Si/p-GaPN/n-GaPN/GaP/Si heterostructure

Here, Akihiro Wakahara and colleagues at Toyohashi University of Technology (Toyohashi Tech) demonstrate the first realization of a one-bit counter circuit OEIC with an optical output consisting of silicon [field effect transistors](#) integrated with gallium phosphide nitride (GaPN) LEDs on a single chip.

The monolithic integrated circuits were fabricated using lattice matched Si/GaPN/Si heterostructures grown on silicon substrates in a dual chamber molecular beam epitaxy (MBE) system. Notably, growth of the silicon capping layer at a high temperature of 850°C led to a dramatic reduction of the threshold voltage to -2.1 V and an increase of the channel mobility of the p-MOSFET to 82 cm²/Vs. This improvement is attributed to a decrease in phosphorus incorporation during the growth of the capping layer.



The one-bit counter circuit fabricated using the n-Si/p-GaPN/n-GaPN/GaP/n-Si heterostructure exhibited normal operation, where red light emission from the input and output indicators was in synchronization with the input and output logical voltages.

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Provided by Toyohashi University of Technology

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